

## DUAL OPERATIONAL AMPLIFIER

The TDA0358D consists of two independent, high gain, internally frequency compensated operational amplifiers. It is especially designed to operate from a single power supply over a wide range of voltages.

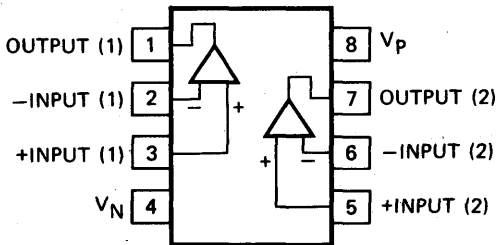
The circuit is equivalent to the LM358, however it is mounted in a miniature plastic package.

The device can be directly operated from the standard +5 V supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional  $\pm 15$  V supplies.

### Features

- Internally frequency compensated for unity gain
- Large d. c. voltage gain : 100 dB
- Unity gain bandwidth : 1 MHz
- Wide supply voltage range : 3 to 30 V
- Low supply current drain : 1 mW per op amp at  $V_P - V_N = 5$  V
- Differential input voltage range equal to supply voltage
- Input common mode range includes ground
- Large output voltage range : 0 to  $V_P - 1,5$  V
- Operating ambient temperature :  $-25$  to  $+85$  °C

### CONNECTION DIAGRAM

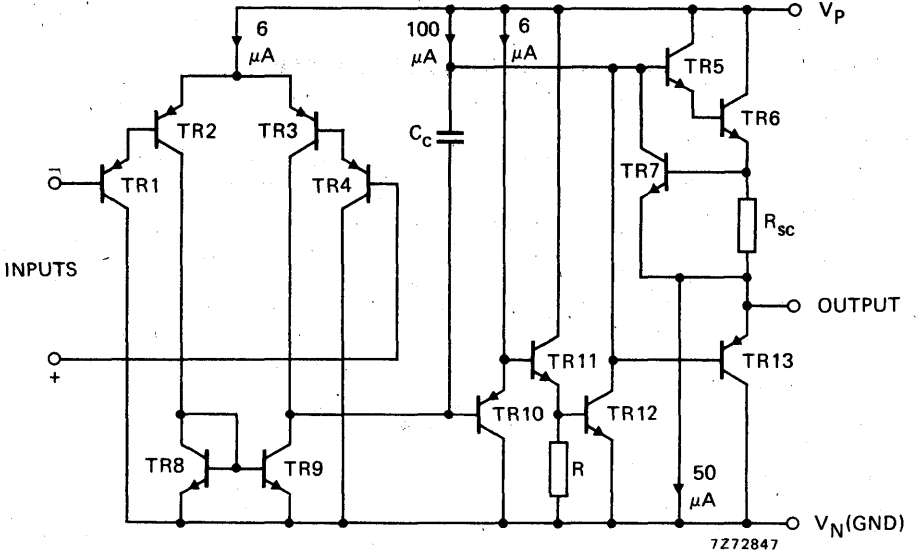


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### PACKAGE OUTLINE (see general section)

SO-8 (SOT-96A); plastic 8-lead flat pack.

CIRCUIT DIAGRAM (one amplifier)



**RATINGS** Limiting values in accordance with the Absolute Maximum System (IEC 134)

Supply voltage	$V_P - V_N$	max.	32	V
Differential input voltage	$V_{I+} - V_{I-}$	max.	$\pm 32$	V
Common mode input voltage	$V_{I+}; V_{I-}$	-0,3 to +32		V
Output short-circuit to $V_N$ (see note)		continuous at $T_{amb} = 25^\circ\text{C}$		$V_P < 15\text{ V}$ , only one amplifier

Temperatures

Operating ambient temperature	$T_{amb}$	-25 to +85	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-65 to +125	$^\circ\text{C}$
Junction temperature	$T_j$	max. 125	$^\circ\text{C}$

Power dissipation in free air;  $T_{amb} = 50^\circ\text{C}$  (see note)

Mounted on a ceramic substrate of $4\text{ cm}^2$	$P_{tot}$	max.	450	mW
derating factor for $T_{amb} > 50^\circ\text{C}$	$1/R_{th}$	=	6	mW/ $^\circ\text{C}$
Mounted on PC board of $4\text{ cm}^2$	$P_{tot}$	max.	310	mW
derating factor for $T_{amb} > 50^\circ\text{C}$	$1/R_{th}$	=	4,2	mW/ $^\circ\text{C}$

Note: Short-circuits from the output to  $V_P$  can cause excessive heating and eventual destruction.  $I_O$  max. is about 40 mA independent of the magnitude of  $V_P$ . At values of  $V_P$  in excess of +15 V, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.

**CHARACTERISTICS** at  $V_P = +5\text{ V}$ ;  $V_N = 0$ ;  $T_{\text{amb}} = 25\text{ }^\circ\text{C}$  unless otherwise specified

Parameter	Conditions	Symbol	min.	typ.	max.	Unit
Input offset voltage		$V_{io}$	-	2	7	mV
Input offset current		$I_{io}$	-	5	50	nA
Input bias current	1)	$I_i$	-	45	500	nA
Common mode input voltage	$V_P \leq 30\text{ V }^2)$	$V_i$	0	-	$V_P - 1,5$	V
Common mode rejection ratio	d. c.	CMRR	-	85	-	dB
Power supply rejection ratio	d. c.	PSRR	-	100	-	dB
Amplifier to amplifier coupling	$f = 1\text{ kHz to } 20\text{ kHz}$ (input referred)		-	-120	-	dB
Large signal voltage gain	$R_L > 2\text{ k}\Omega$	$G_V$	-	100	-	V/mV
Output voltage range	$R_L > 2\text{ k}\Omega$	$V_o$	0	-	$V_P - 1,5$	V
Output current source	$V_{I+} = 1\text{ V}; V_{I-} = 0\text{ V}$	$I_o$	20	40	-	mA
Output current sink	$V_{I+} = 0\text{ V}; V_{I-} = 1\text{ V}$	$I_o$	10	20	-	mA
Supply current	$R_L = \infty$ (all op amps)	$I_P$	-	0,5	1,2	mA

1) The direction of the input current is out of the IC due to the p-n-p input stage.

2) Either input signal voltage should not be allowed to go negative by more than 0,3 V. The upper end of the common mode voltage range is  $V_P - 1,5\text{ V}$ , but either or both inputs can go to +30 V without damage.